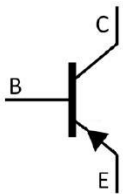


TO-126F PNP Silicon PNP transistor in a TO-126F Plastic Package.

I_C $V_{CE(sat)}$
 High I_C , low $V_{CE(sat)}$.

Strobe flash applications, audio power amplifier applications.

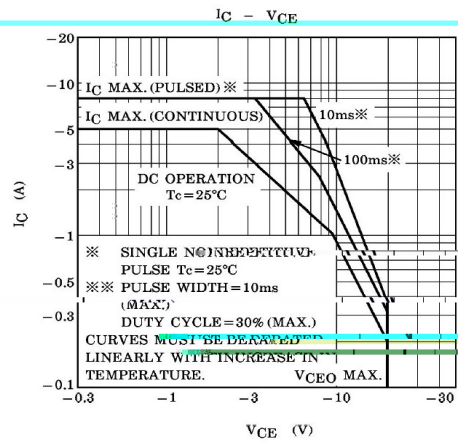
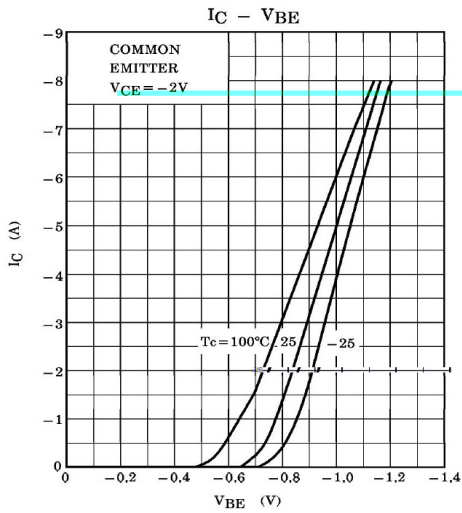
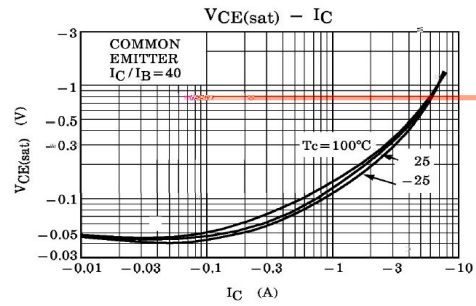
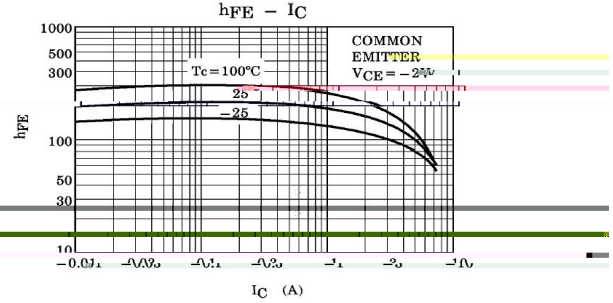
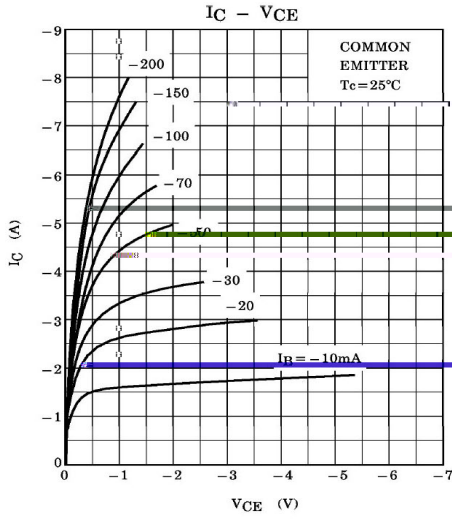


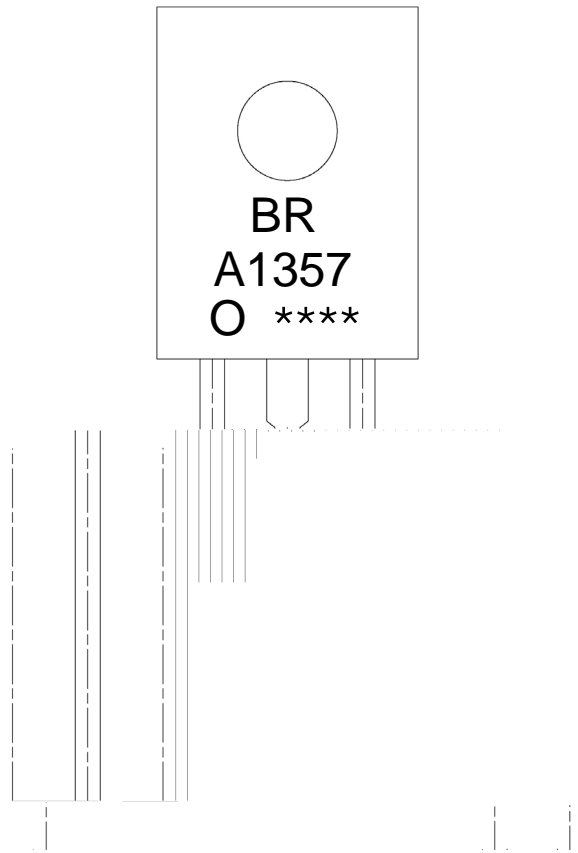
PIN1 Emitter PIN 2 Collector PIN 3 Base

h_{FE} Classifications Symbol	O	Y
h_{FE} Range	100 200	160 320

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-35	V
Collector to Emitter Voltage	V_{CEO}	-20	V
Emitter to Base Voltage	V_{EBO}	-8.0	V
Collector Current - Continuous	I_C	-5.0	A
Collector Current – Continuous(Pulse)	I_{CP}	-8.0	A
Base Current – Continuous	I_B	-1.0	A
Collector Power Dissipation	P_C	1.5	W
Collector Power Dissipation	$P_C(T_C=25 \text{ }^\circ\text{C})$	10	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Emitter Breakdown Voltage	V					





BR

A1357

O: h_{FE}

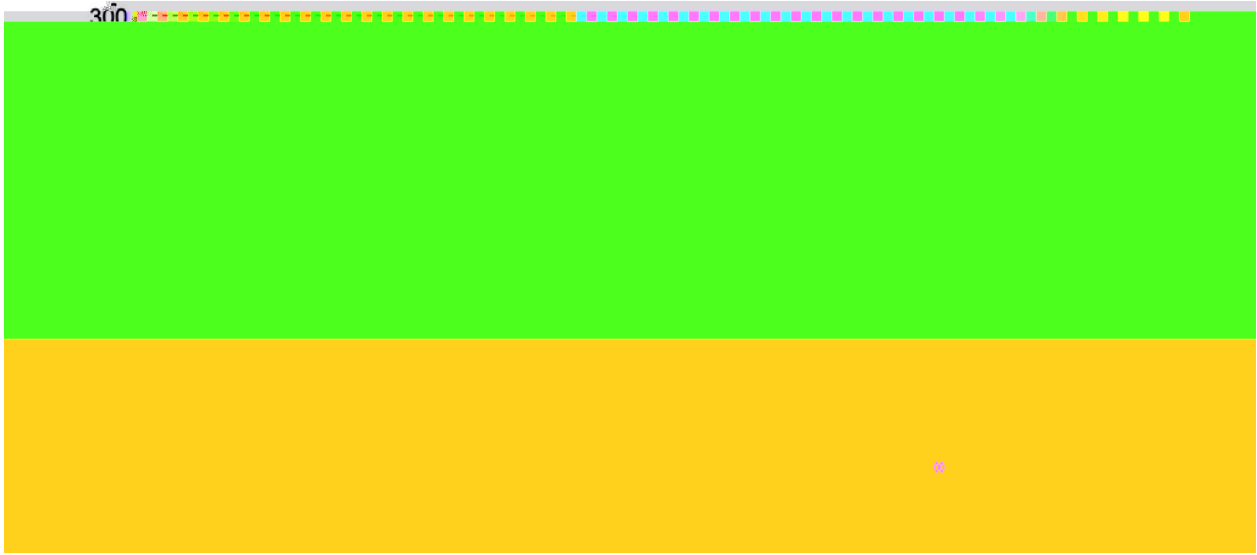
Note:

BR: Company Code

A1357: Product Type.

O: h_{FE} Classifications Symbol

****: Lot No. Code, code change with Lot No.



1	25	150	60	90sec;	Note: 1.Preheating:25~150 , Time:60~90sec. 2.Peak Temp.:255±5 , Duration:5± 0.5sec. 3. Cooling Speed: 2~10 /sec.
2	255±5		5± 0.5sec;		
3		2	10 /sec.		

270±5 10± 1 sec. Temp.:270±5 Time:10±1 sec

/ BULK

Package Type	Units		Dimension	(unit mm ³)
	Units/Tube /	Tubes/Inner Box /		